Switch Mode Power Rectifiers

DPAK-3 Surface Mount Package

These state-of-the-art devices are designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Extremely Fast Switching
- Extremely Low Forward Drop
- Platinum Barrier with Avalanche Guardrings
- NRVBD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 0.4 Gram (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Ratings:
 - ◆ Machine Model = C
 - ◆ Human Body Model = 3B



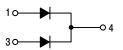
ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIERS 6.0 AMPERES, 20 – 60 VOLTS



DPAK CASE 369C



MARKING DIAGRAM



Y = Year WW = Work Week B6x0T = Device Code x = 2, 3, 4, 5, or 6 G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

| | | MBRD/NRVBD/SBR | | | | | |
|--|--|----------------|-------|-------|-------|-------|------|
| Rating | Symbol | 620CT | 630CT | 640CT | 650CT | 660CT | Unit |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 20 | 30 | 40 | 50 | 60 | V |
| Average Rectified Forward Current T _C = 130°C (Rated V _R) Per Diode Per Device | I _{F(AV)} | 3 6 | | | | А | |
| Peak Repetitive Forward Current, T _C = 130°C (Rated V _R , Square Wave, 20 kHz) Per Diode | I _{FRM} | 6 | | | | Α | |
| Nonrepetitive Peak Surge Current – (Surge applied at rated load conditions halfwave, single phase, 60 Hz) | I _{FSM} | 75 | | | Α | | |
| Peak Repetitive Reverse Surge Current (2 μs, 1 kHz) | I _{RRM} | 1 | | | Α | | |
| Operating Junction Temperature (Note 1) | TJ | -65 to +175 | | | °C | | |
| Storage Temperature | T _{stg} | -65 to +175 | | | °C | | |
| Voltage Rate of Change (Rated V _R) | dv/dt | 10,000 | | | V/μs | | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS PER DIODE

| Characteristic | | Value | Unit | |
|--|----------------|-------|------|--|
| Maximum Thermal Resistance, Junction-to-Case | $R_{	heta JC}$ | 6 | °C/W | |
| Maximum Thermal Resistance, Junction-to-Ambient (Note 2) | $R_{	heta JA}$ | 80 | °C/W | |

^{2.} Rating applies when surface mounted on the minimum pad size recommended.

ELECTRICAL CHARACTERISTICS PER DIODE

| Characteristic | Symbol | Value | Unit |
|---|----------------|----------------------------|------|
| Maximum Instantaneous Forward Voltage (Note 3) $ \begin{aligned} & i_F = 3 \text{ Amps, } T_C = 25^{\circ}\text{C} \\ & i_F = 3 \text{ Amps, } T_C = 125^{\circ}\text{C} \\ & i_F = 6 \text{ Amps, } T_C = 25^{\circ}\text{C} \\ & i_F = 6 \text{ Amps, } T_C = 125^{\circ}\text{C} \end{aligned} $ | V _F | 0.7 0.65 0.9 0.85 | V |
| Maximum Instantaneous Reverse Current (Note 3) (Rated dc Voltage, $T_C = 25^{\circ}C$) (Rated dc Voltage, $T_C = 125^{\circ}C$) | i _R | 0.1 15 | mA |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

The heat generated must be less than the thermal conductivity from Junction-to-Ambient: dP_D/dT_J < 1/R_{θJA}.

^{3.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS

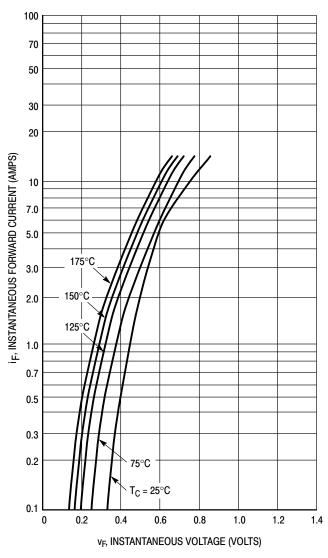
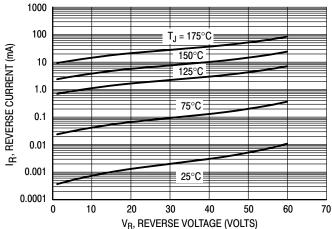


Figure 1. Typical Forward Voltage, Per Leg



*The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these curves if V_R is sufficient below rated V_R .

Figure 2. Typical Reverse Current,* Per Leg

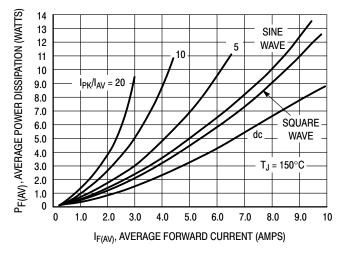


Figure 3. Average Power Dissipation, Per Leg

TYPICAL CHARACTERISTICS

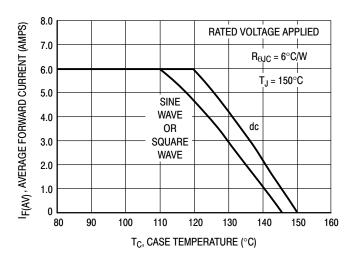


Figure 4. Current Derating, Case, Per Leg

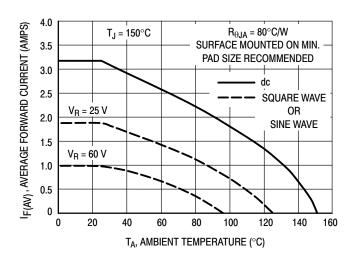


Figure 5. Current Derating, Ambient, Per Leg

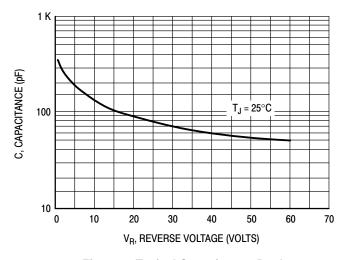


Figure 6. Typical Capacitance, Per Leg

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|-------------------|-----------------------|
| MBRD620CTT4G | | 2500 / Tape & Reel |
| MBRD630CTT4G | | 2500 / Tape & Reel |
| MBRD640CTG | | 75 Units / Rail |
| NRVBD640CTG* | DPAK (Pb-Free) | 75 Units / Rail |
| MBRD640CTT4G | | 2500 / Tape & Reel |
| NRVBD640CTT4G* | | 2500 / Tape & Reel |
| MBRD650CTG | | 75 Units / Rail |
| MBRD650CTT4G | | 2500 / Tape & Reel |
| NRVBD650CTT4G* | | 2500 / Tape & Reel |
| MBRD660CTG | | 75 Units / Rail |
| NRVBD660CTG* | | 75 Units / Rail |
| MBRD660CTRLG | | 1800 / Tape & Reel |
| NRVBD660CTRLG* | | 1800 / Tape & Reel |
| MBRD660CTT4G | | 2500 / Tape & Reel |
| NRVBD660CTT4G* | | 2500 / Tape & Reel |

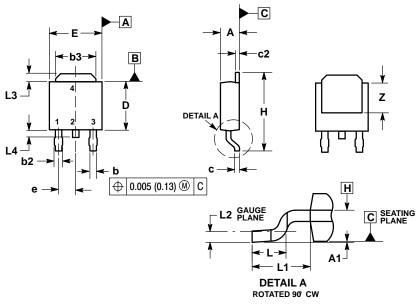
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NRVBD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)

CASE 369C ISSUE D

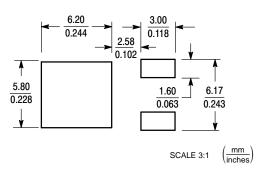


- 1. DIMENSIONING AND TOLERANCING PER ASME
- 714.5M, 1994.
 2. CONTROLLING DIMENSION: INCHES.
 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-
- MENSIONS b3, L3 and Z.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL
- NOT EXCEED 0.006 INCHES PER SIDE.

 5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 6. DATUMS A AND B ARE DETERMINED AT DATUM

| | INC | HES | MILLIMETERS | | | |
|-----|-----------|-----------|-------------|----------|--|--|
| DIM | MIN | MAX | MIN | MAX | | |
| Α | 0.086 | 0.094 | 2.18 | 2.38 | | |
| A1 | 0.000 | 0.005 | 0.00 | 0.13 | | |
| b | 0.025 | 0.035 | 0.63 | 0.89 | | |
| b2 | 0.030 | 0.045 | 0.76 | 1.14 | | |
| b3 | 0.180 | 0.215 | 4.57 | 5.46 | | |
| С | 0.018 | 0.024 | 0.46 | 0.61 | | |
| c2 | 0.018 | 0.024 | 0.46 | 0.61 | | |
| D | 0.235 | 0.245 | 5.97 | 6.22 | | |
| E | 0.250 | 0.265 | 6.35 | 6.73 | | |
| е | 0.090 | 0.090 BSC | | 2.29 BSC | | |
| Н | 0.370 | 0.410 | 9.40 | 10.41 | | |
| L | 0.055 | 0.070 | 1.40 | 1.78 | | |
| L1 | 0.108 REF | | 2.74 REF | | | |
| L2 | 0.020 | BSC | 0.51 BSC | | | |
| L3 | 0.035 | 0.050 | 0.89 | 1.27 | | |
| L4 | | 0.040 | | 1.01 | | |
| Z | 0.155 | | 3.93 | | | |

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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